

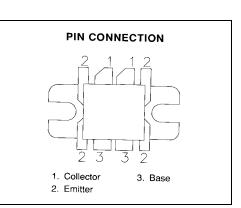
### **RF & MICROWAVE TRANSISTORS** TV/LINEAR APPLICATIONS

### Features

- 500 MHz
- 28 VOLTS
- Pout = 100 WATTS
- $G_P = 5.5 \text{ dB GAIN MINIMUM}$
- EFFICIENCY 55%
- GOLD METALLIZATION
- COMMON EMITTER CONFIGURATION

## DESCRIPTION:

The MS1509 is a 28 V gold metallized, Class C epitaxial silicon NPN planar transistor designed for UHF military and commercial equipment. The MS1508 is an internally matched, broadband device optimized for operation within the 100 – 500 MHz frequency range. This device utilizes diffused emitter resistors to achieve 5:1 VSWR load mismatch capability at rated operating conditions.



## ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

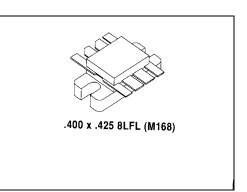
Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	33	V
V <sub>CES</sub>	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
I <sub>C</sub>	Device Current	15	Α
PDISS	Power Dissipation	260	W
TJ	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

## Thermal Data

R <sub>TH(J-C)</sub> Thermal Resistance Junction-case	0.67	°C/W
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**MS1509** 



# MS1509

# ELECTRICAL SPECIFICATIONS (Tcase = $25^{\circ}$ C)

STATIC

Symbol		Test Conditions		Value		
			Min.	Typ.	Max.	Unit
BV <sub>CBO</sub>	l <sub>c</sub> = 100 mA	I <sub>E</sub> = 0 mA	60			V
<b>BV</b> <sub>CES</sub>	I <sub>c</sub> = 80 mA	$V_{BE} = 0 V$	60			V
BV <sub>CEO</sub>	l <sub>c</sub> = 50 mA	I <sub>B</sub> = 0 mA	33			V
<b>BV</b> <sub>EBO</sub>	I <sub>E</sub> = 20 mA	$I_c = 0 mA$	4.0			V
I <sub>CBO</sub>	V <sub>CB</sub> = 30 V	I <sub>E</sub> = 0 mA			10	mA
HFE	$V_{CE} = 5 V$	I <sub>c</sub> = 1 mA	20			

## DYNAMIC

Symbol	Test Conditions			Value			
				Min.	Typ.	Max.	Unit
Pout	f = 500 MHz	P <sub>IN</sub> =28.2 W	$V_{cc} = 28 V$	100			w
G <sub>P</sub>	f = 500 MHz	P <sub>IN</sub> = 28.2 W	$V_{cc} = 28 V$	5.5			dB
ηc	f = 500 MHz	P <sub>IN</sub> = 28.2 W	V <sub>cc</sub> = 28 V	55			%

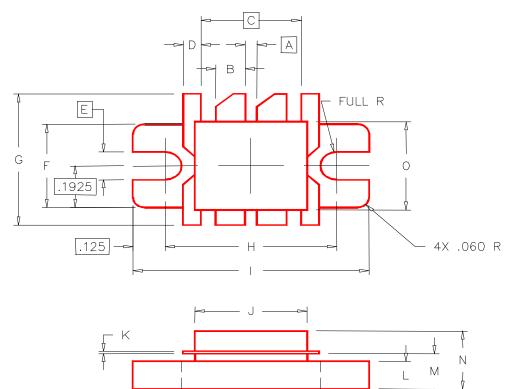


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## PACKAGE MECHANI CAL DATA

PACKAGE STYLE M168



	MINIMUM	MAXIMUM		MINIMUM	
	INCHES/MM	INCHES/MM		INCHES/MM	INCHES/MM
Α	.030/0,76		I	.895/22,73	.905/22,99
В	.115/2,92	.125/3,18	J	.420/10,67	.430/10,92
С	.360/9,14		K	.003/0,08	.007/0,18
D	.065/1,65	.075/1,91	L	.120/3,05	.130/3,30
E	.130/3,30		М	.159/4,04	.175/4,45
F	.380/9,65	.390/9,91	Ν		.280/7,11
G	.735/18,67	.765/19,43	0	.395/10,03	.405/10,29
Н	.645/16,38	.655/16,64			

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